

# Dilute magnetic semiconductors

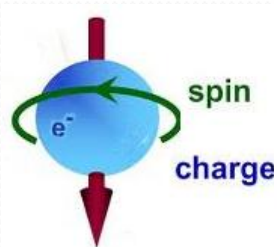
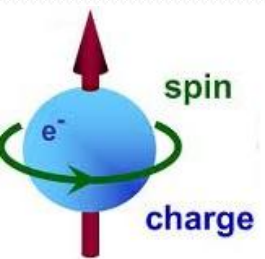
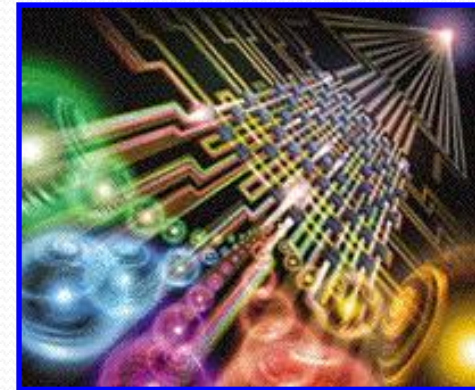
Iuliia Mikulska

University of Nova Gorica

Doctoral study, programme physics

# Spintronics

- Spintronics (a neologism meaning "spin transport electronics"), also known as magnetoelectronics or spin electronics.



Terminal



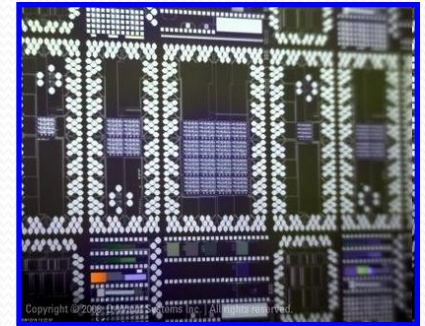
## Memory storage



## Magnetic sensors



## Quantum computing

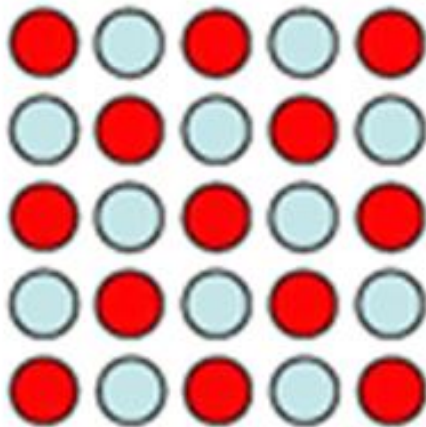


## Primary requirements for spintronic materials:

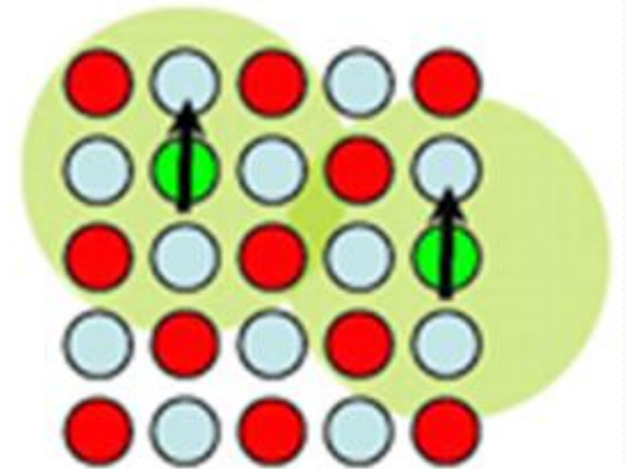
- Room temperature ferromagnetism.
- Compatible with electronic devices.
- Semiconducting and ferromagnetic properties should coexist at room temperature.

# Dilute Magnetic Semiconductors (DMS)

Nonmagnetic  
Semiconductor  
Crystal



Ferromagnetic  
DMS



Add TM Ions



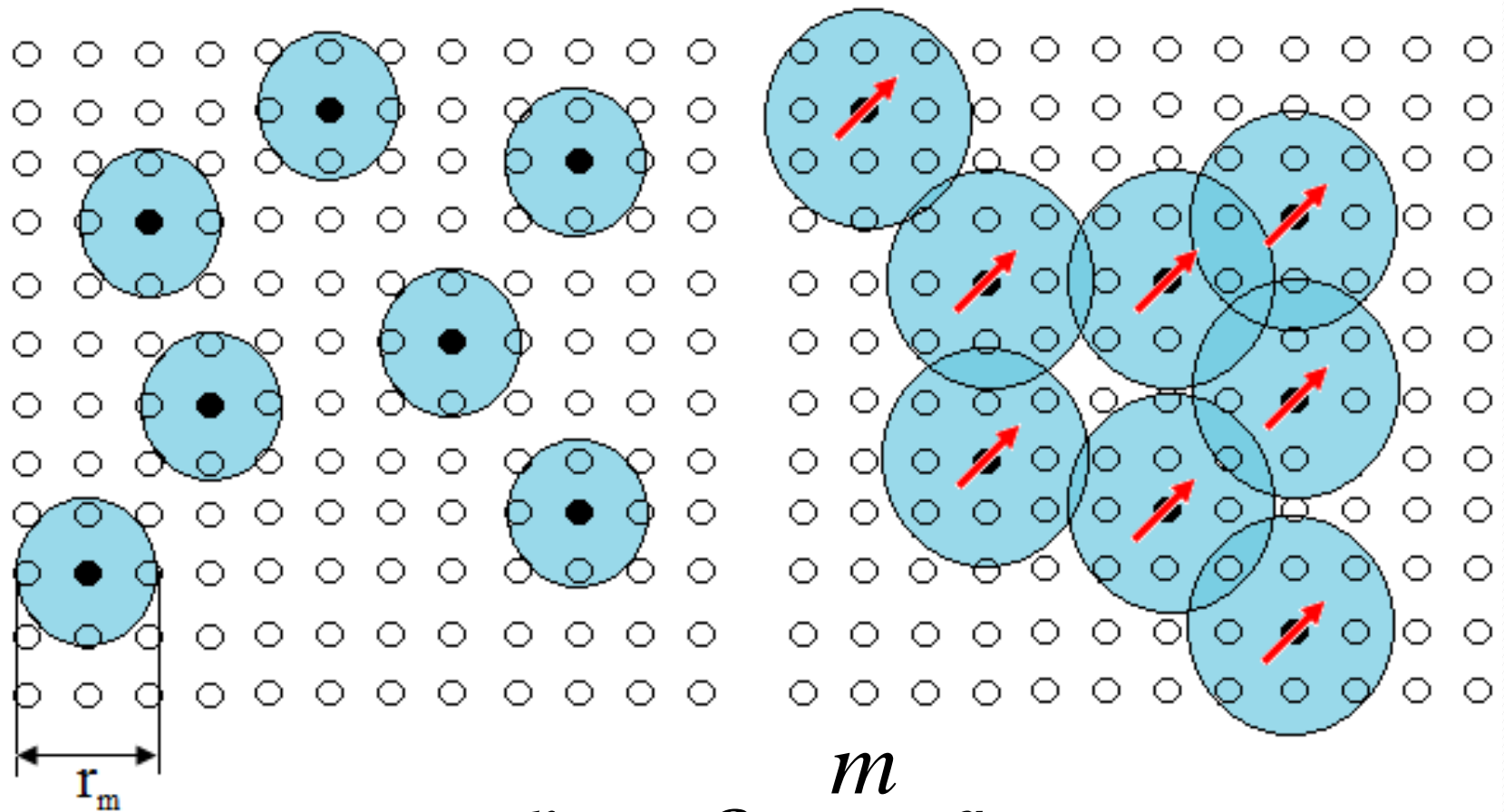
Mn, Fe, Co

GaAs, ZnO, AlN, TiO<sub>2</sub>

Typical representatives.

- Mn-doped GaAs
- Mn-doped ZnO

# When the magnetic coupling occur in the doped semiconductors?

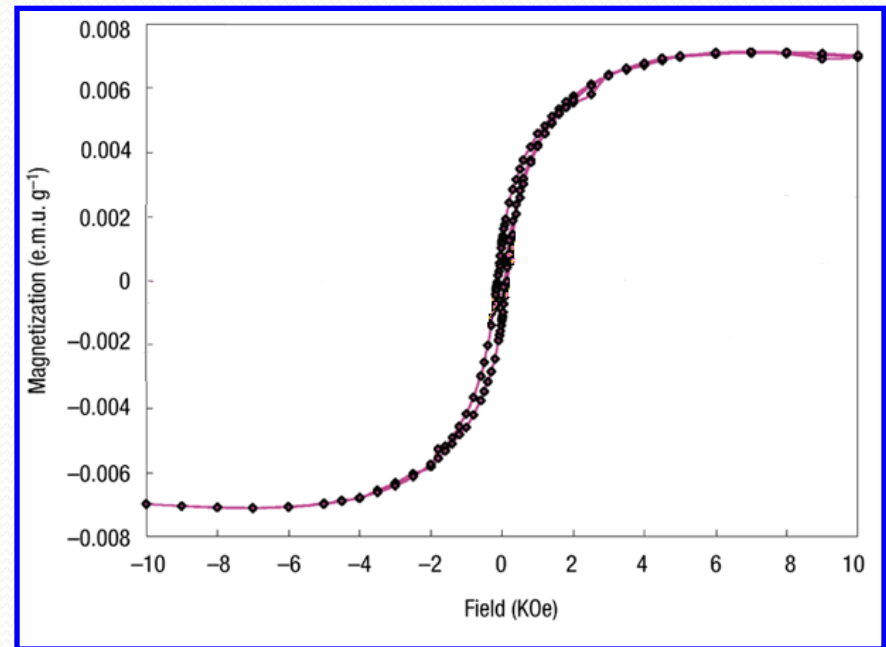


$$r_m = \epsilon_r \frac{m}{m^*} a_0$$

# Ferromagnetism in bulk Mn-doped ZnO

- No trace of any secondary phase or other impurities was found.
- Room temperature ferromagnetism discovered in Mn doped ZnO [1].

Hysteresis curve at Room temperature  
for 2 at. % Mn-doped ZnO

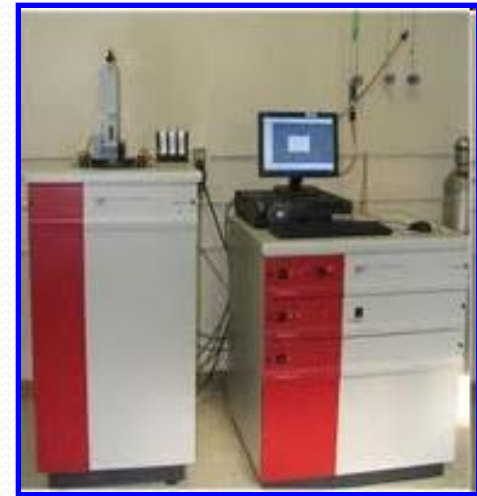


In general, the solid solubility of transition metals in semiconductors is low.



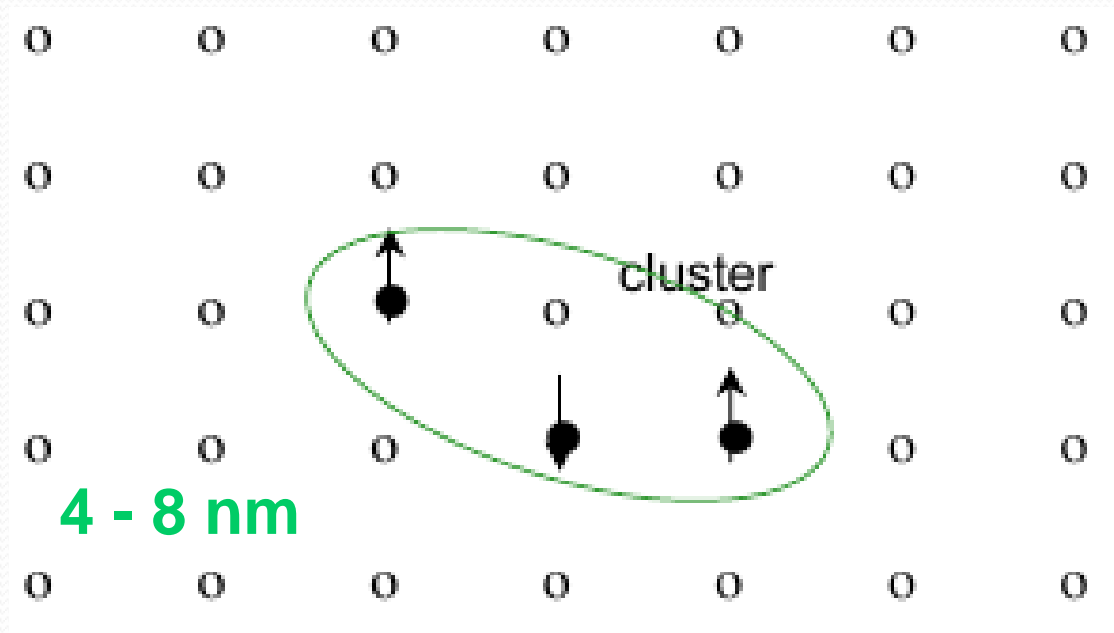
# Type of impurity source of magnetism in DMS systems

- Clusters \ Segregations
- Secondary Phases (Spinels)
- Extrinsic impurity



- SQUID magnetometer  
(superconducting quantum  
interference devices)

# Clusters

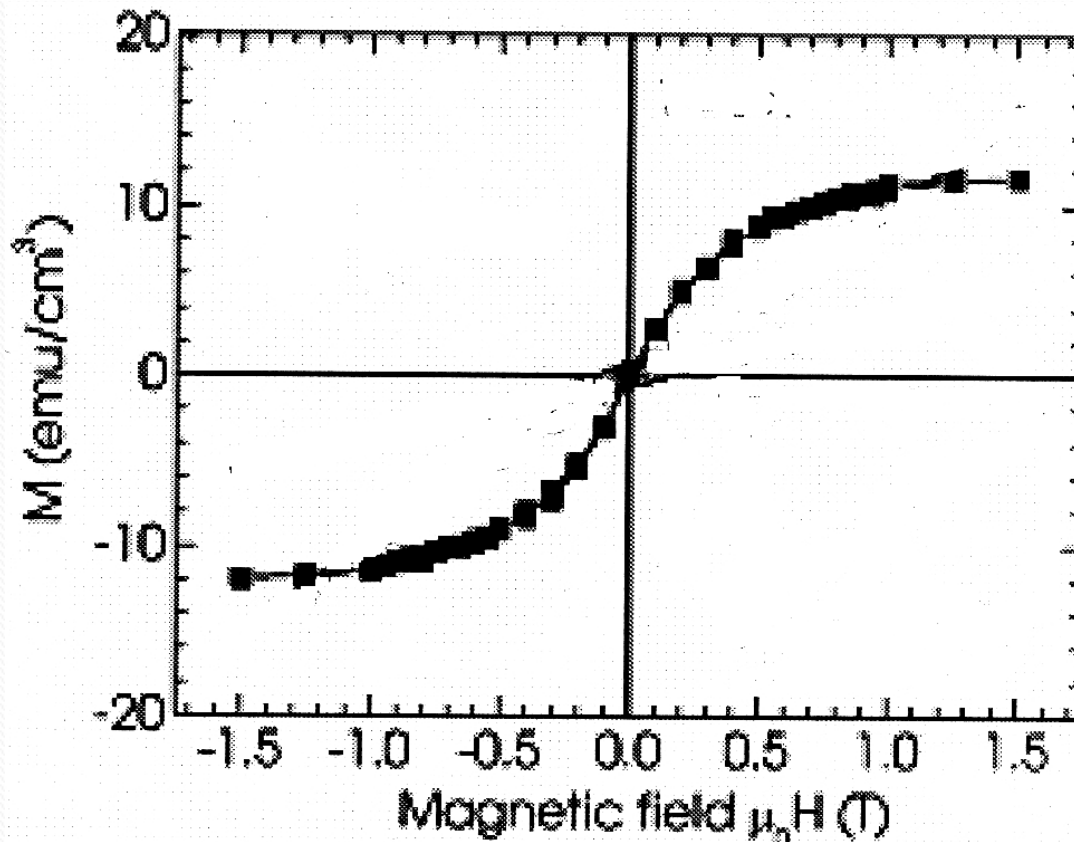


- Nanoclusters of the TM ion form the most obvious candidates for impurity sources of magnetism.



# Secondary Phases (Spinel)

Hysteresis curve for  $\text{ZnCo}_2\text{O}_4$   
phase in the Co-doped ZnO



general formula



# Extrinsic impurities

- Magnetic moment of small amount extrinsic impurity is

$$\mu = 5 * 10^{-6} \text{ emu}$$

- Abraham undertook a systematic study of the growth of  $\text{HfO}_2$  thin films [2].
- No ferromagnetic signal
- Observation of a magnetic signal



- Teflon tweezers

- Stainless steel tweezers



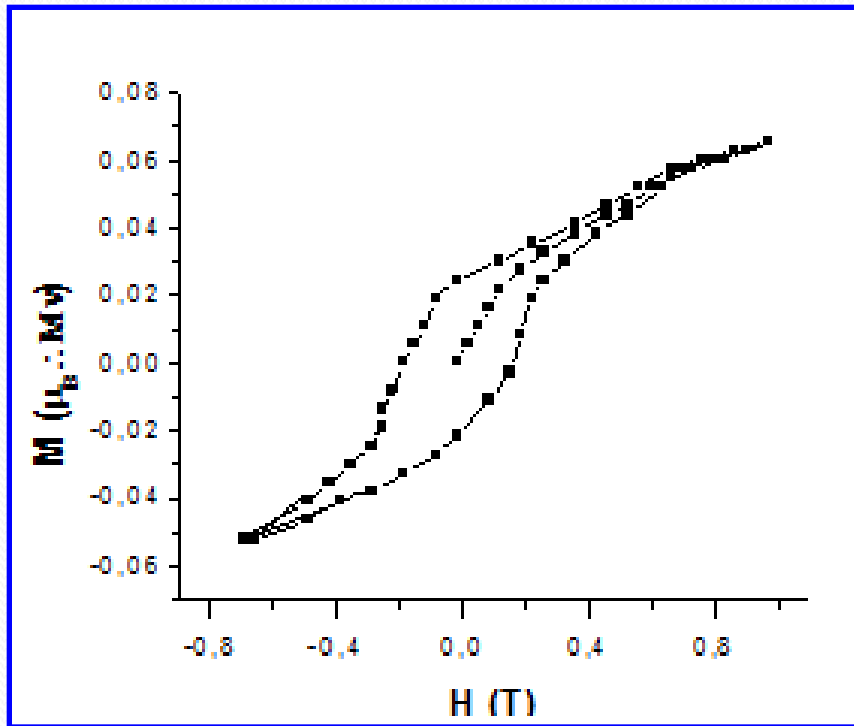
# Metal doped $\text{In}_2\text{O}_3$

- 1. Nanocrystalline  $\text{In}_2\text{O}_3$  is **diamagnetic**.
- 2. Bulk TM-doped (M = Cr, Mn, Fe, Ni, Cu)  $\text{In}_2\text{O}_3$  is intrinsically **paramagnetic**, with a paramagnetic effective moment originating from the dopant.
- 3. **Magnetic behaviour** in bulk material are linked to the presence of small amounts of **magnetic secondary phases** in the samples.

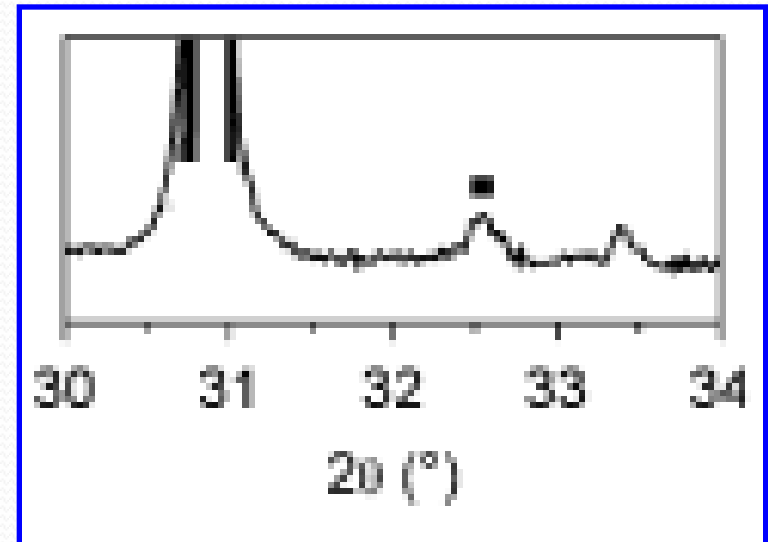
**Magnetic phenomena** in DMS have been attributed to experimental artefact, such as influence of **synthesis conditions** or **measurements errors**.

# Mn – doped $\text{In}_2\text{O}_3$

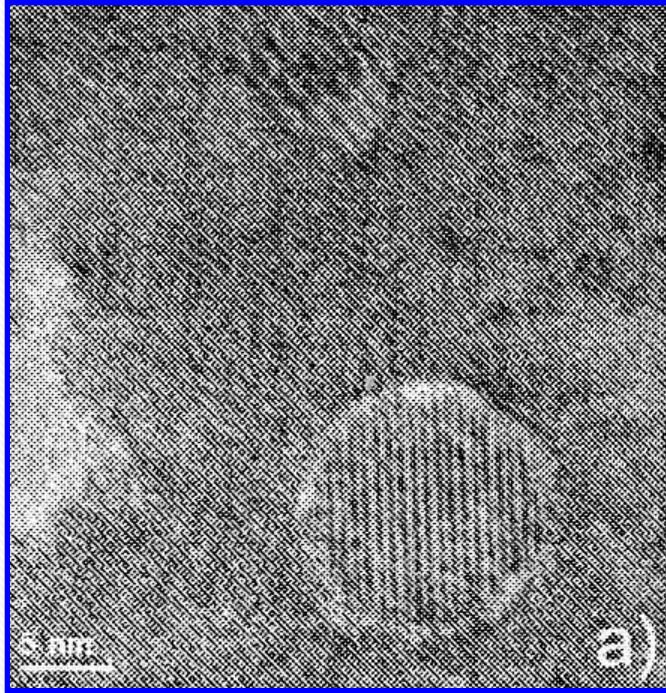
Hysteresis loop in Mn-doped  $\text{In}_2\text{O}_3$



XRD spectrum from the sample showing the presence of oriented  $\text{Mn}_2\text{O}_3$  fractions.



# Transmission electron microscope (TEM)

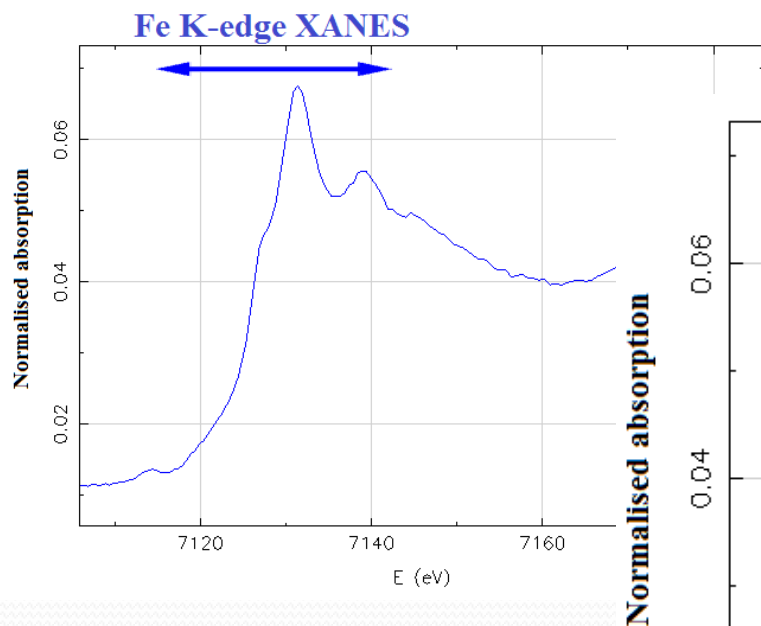


High resolution TEM of Ge:Mn film showing Mn<sub>5</sub>Ge<sub>3</sub> clusters

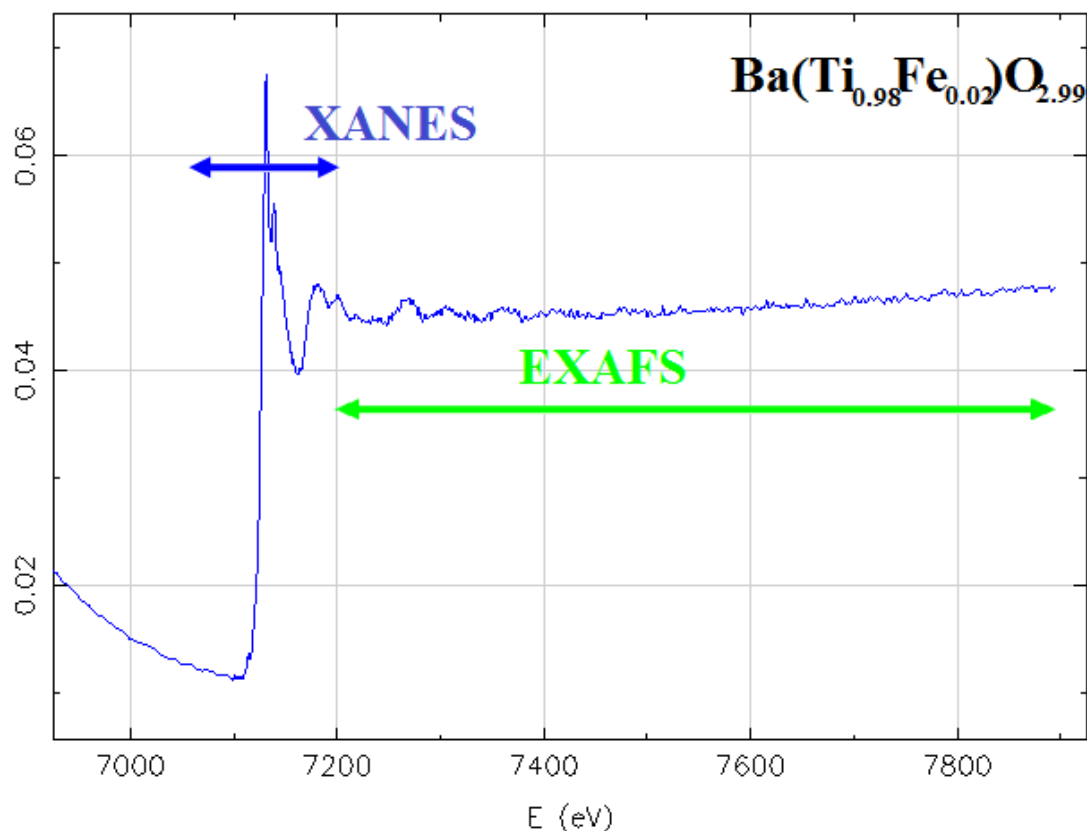
- The dilution of TM ions used to dope these DMS materials means that it is quite conceivable that the cross section does not contain any such impurities.[6]



# X-Ray Absorption Spectroscopy (XAS)

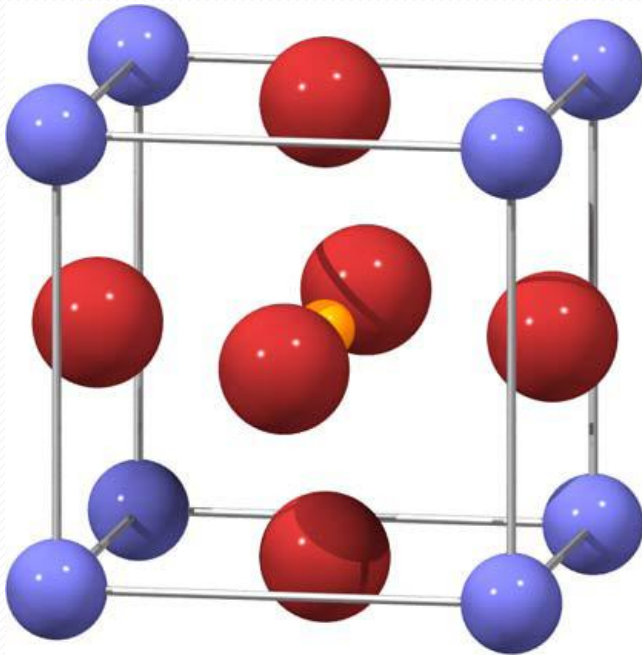


Fe K- edge XANES  
spectra of  
 $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$



Normalised Fe K-shell absorption  
spectra of  $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$

# Fe doped BaTiO<sub>3</sub>



- BaTiO<sub>3</sub> – ferroelectric material with perovskite structure

Doping with iron:

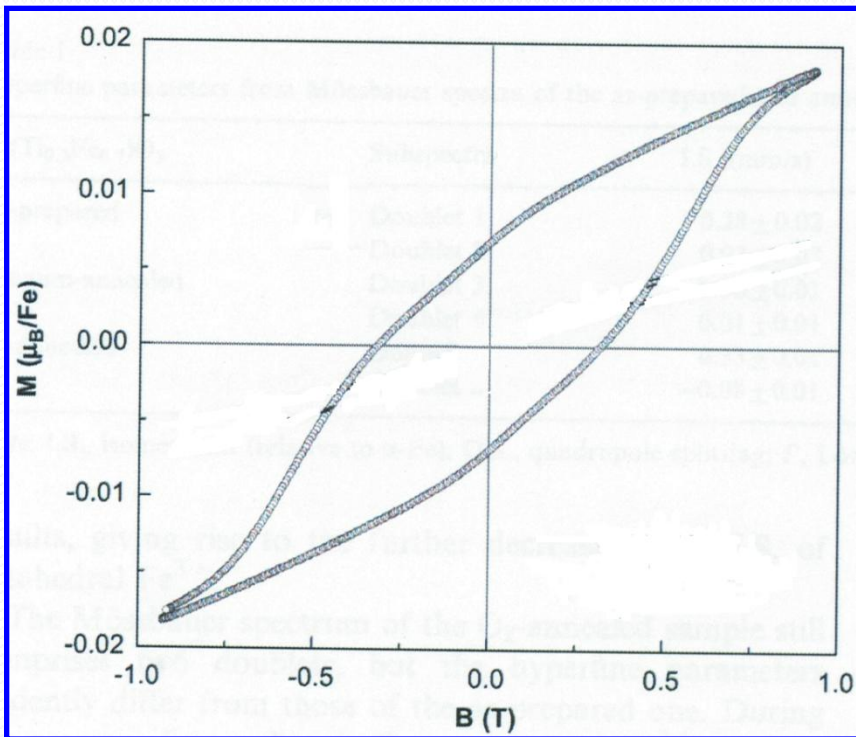


aliovalent substitution

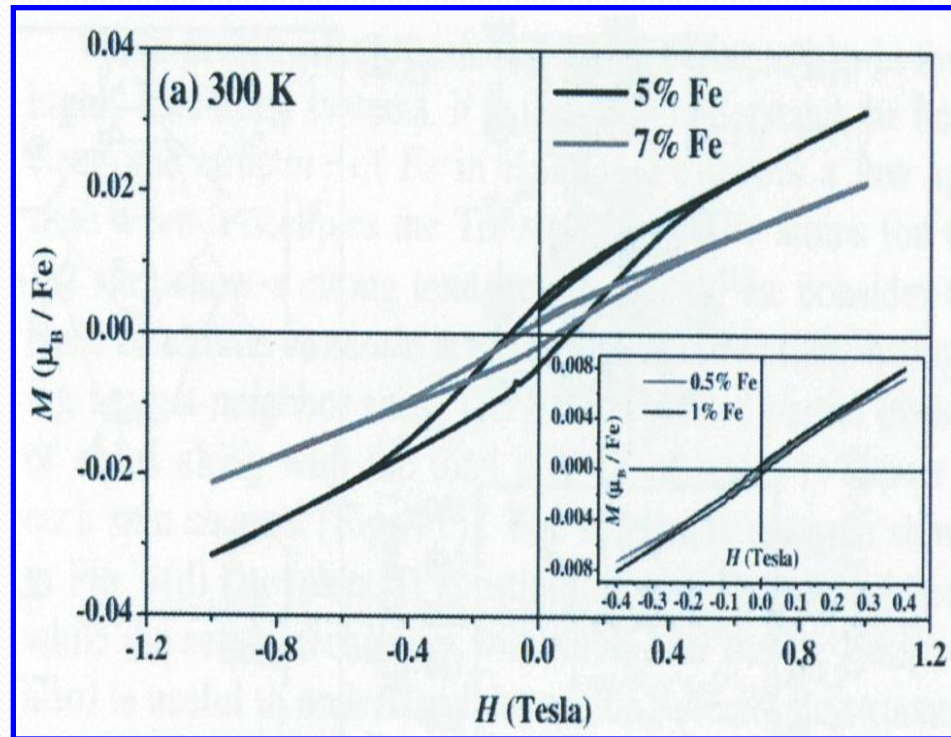


# Room temperature ferromagnetism in Fe doped BaTiO<sub>3</sub>

Room-temperature M–H curves of the O<sub>2</sub>-annealed Ba(Ti<sub>0.3</sub>Fe<sub>0.7</sub>)O<sub>3</sub> ceramic [8]



Room temperature M(H) loops from samples Ba(Ti<sub>0.95</sub>Fe<sub>0.05</sub>)O<sub>3</sub> and Ba(Ti<sub>0.93</sub>Fe<sub>0.07</sub>)O<sub>3</sub> [9]

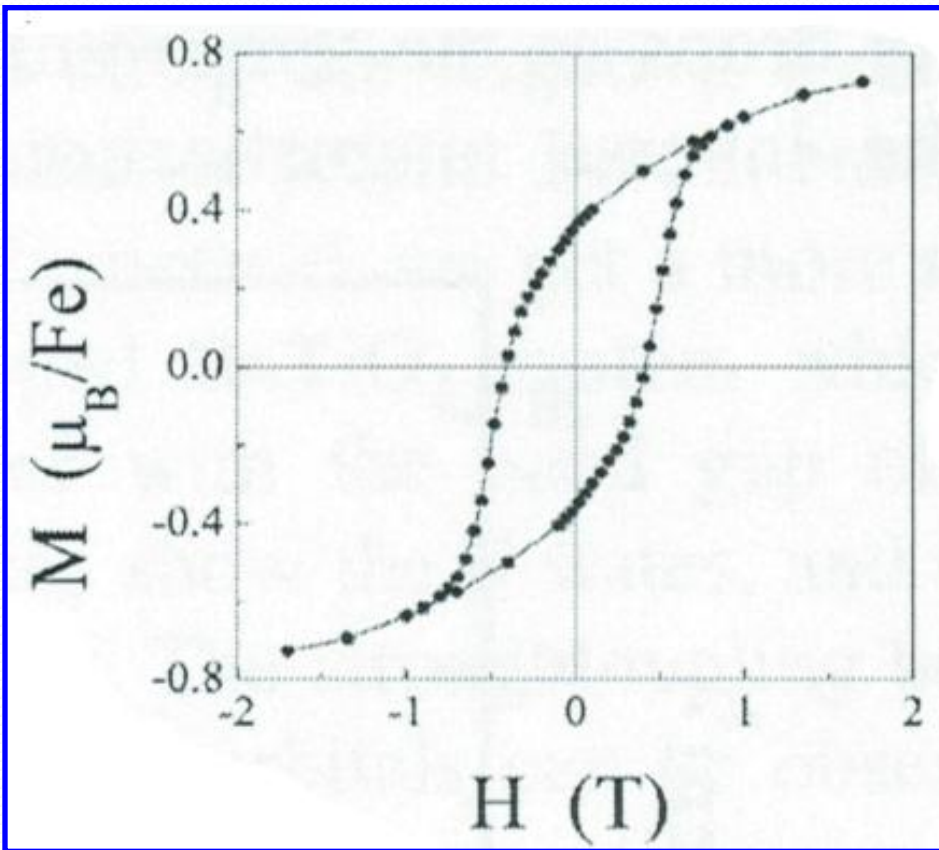


8. Fangting Lin, Dongmei Jiang, et al., Physica B 403, p. 2525-2529, 2008.

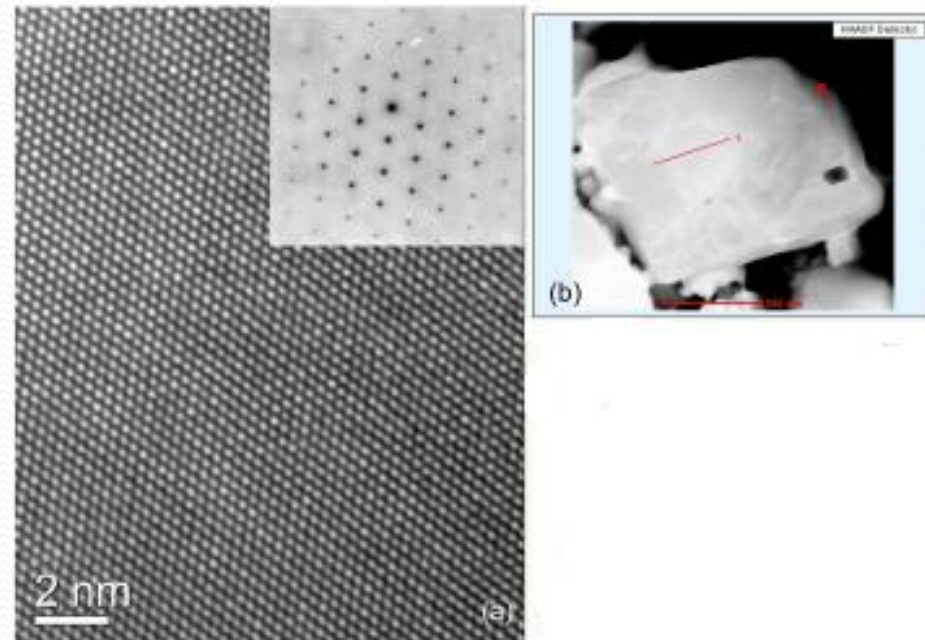
9. Sugata Ray, Priya Mahadevan, et al. Physical Review B 77, p. 104416 (2008)

# Room temperature ferromagnetism in Fe doped $\text{BaTiO}_3$

Magnetic hysteresis loop of the  $\text{BaTi}_{0.95}\text{Fe}_{0.05}\text{O}_3$  ceramics at room temperature



(a) High-resolution transmission electron microscopy of the  $\text{BaTi}_{0.95}\text{Fe}_{0.05}\text{O}_3$  ceramics, and selected area electron diffraction in the inset; (b) transmission electron microscopy the  $\text{BaTi}_{0.95}\text{Fe}_{0.05}\text{O}_3$  ceramics;



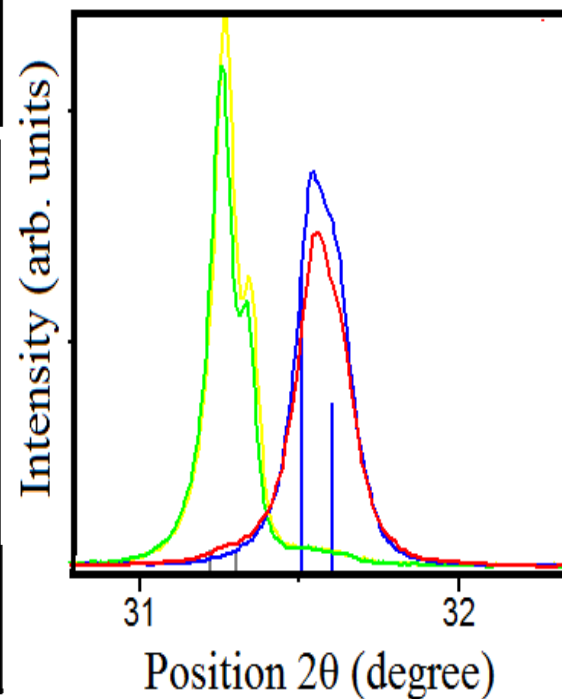
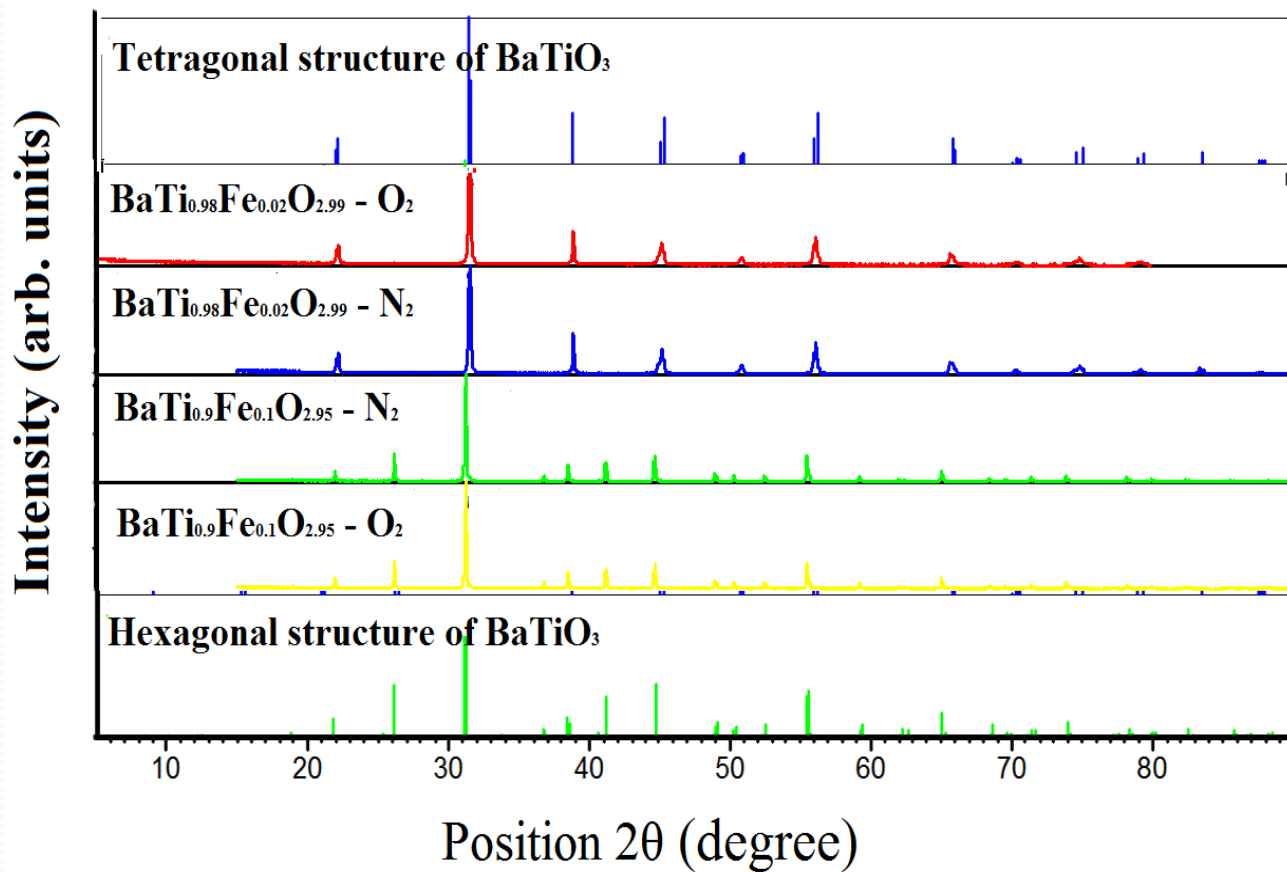
# Our study: Fe-doped BaTiO<sub>3</sub>

- The purpose of this research is detailed studies on the existence of the intrinsic magnetic ordering in Fe doped BaTiO<sub>3</sub>.

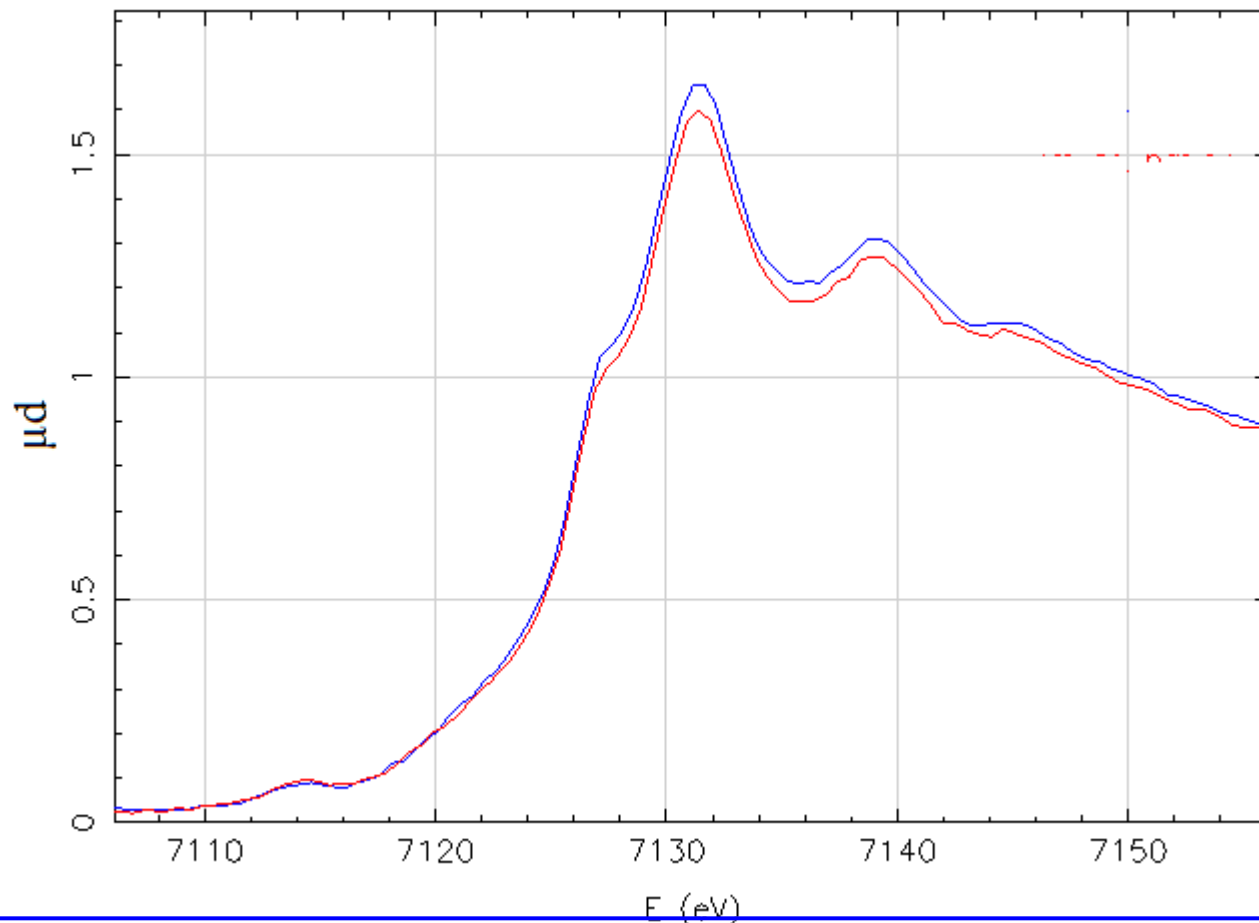
# Our study: Fe-doped BaTiO<sub>3</sub>

- Sample preparation:
  - Solid state reaction method.
  - Ba(Ti<sub>1-x</sub>Fe<sub>x</sub>)O<sub>3-x/2</sub>, where x=2, 10 % of Fe –synthesis in nitrogen 1250°C/5h.
  - Ba(Ti<sub>1-x</sub>Fe<sub>x</sub>)O<sub>3-x/2</sub>, where x=2, 10 % of Fe –synthesis in oxygen 1250°C/5h.
- X-Ray Diffraction (XRD).
- X-Ray Absorption Spectroscopy (XAS).
- Magnetic measurements.

# XRD patterns



# Fe K-edge XANES spectra in $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$

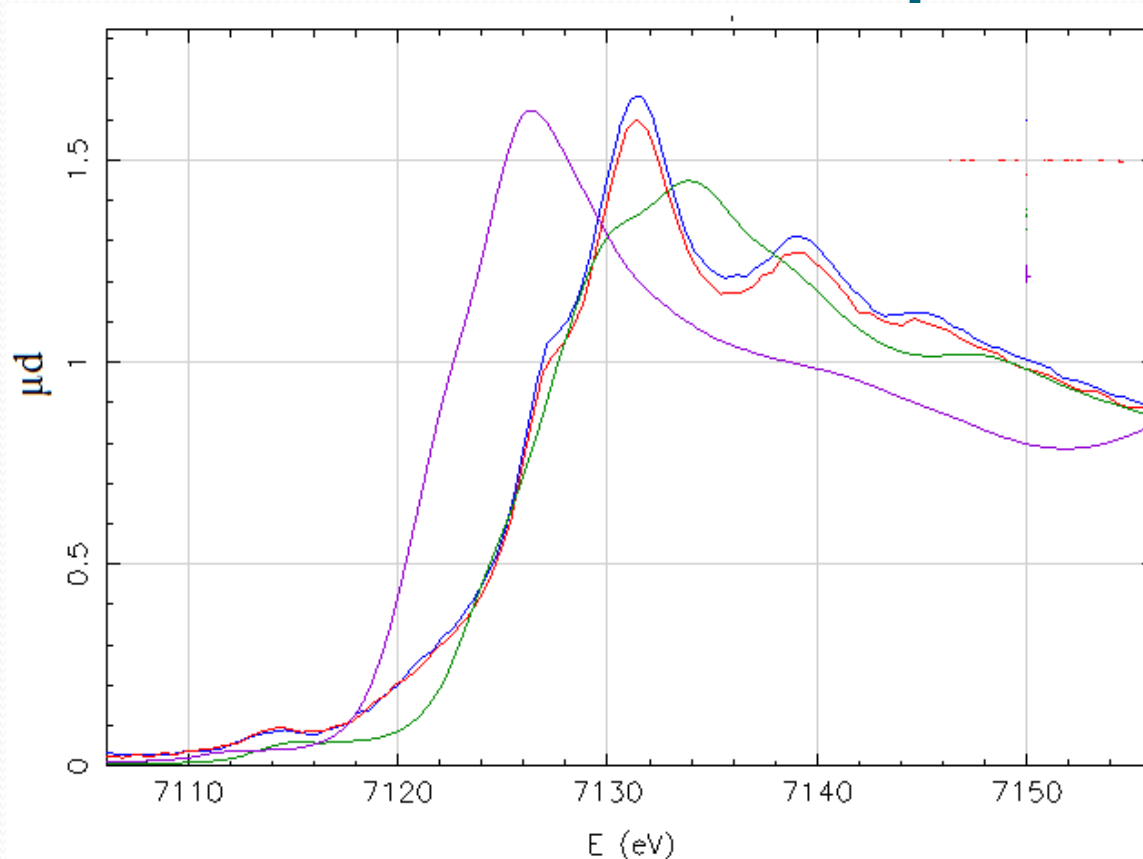


Fe K- edge XANES spectra of  $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$   
(blue line – annealed in nitrogen, red line – in oxygen)



# Valence state of Fe in

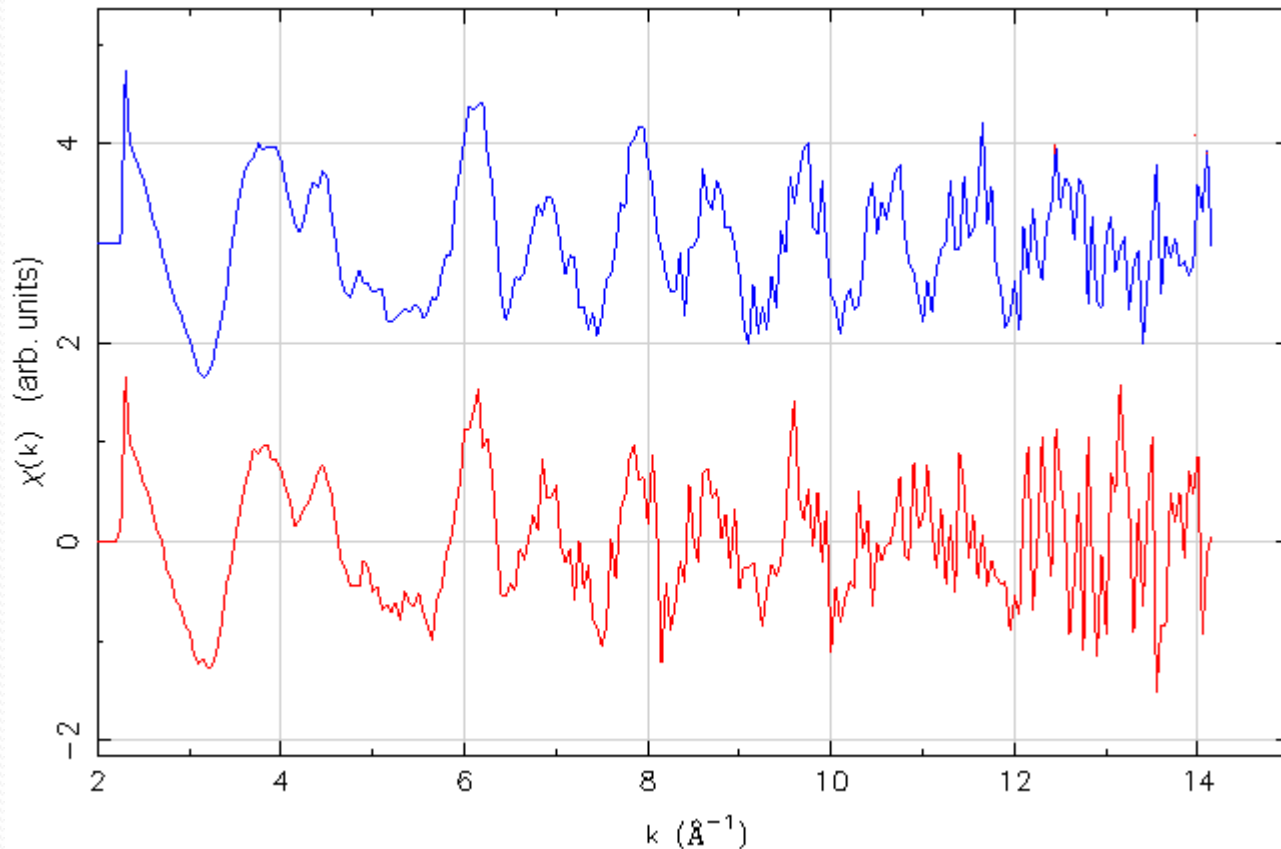
# Fe doped BaTiO<sub>3</sub>



Fe K- edge XANES spectra of Ba(Ti<sub>0.98</sub>Fe<sub>0.02</sub>)O<sub>2.99</sub> (blue line – annealed in nitrogen, red line – in oxygen) and reference samples (light violet line – FeSO<sub>4</sub>, green line – Fe<sub>2</sub>O<sub>3</sub>) with well known Fe valence state.



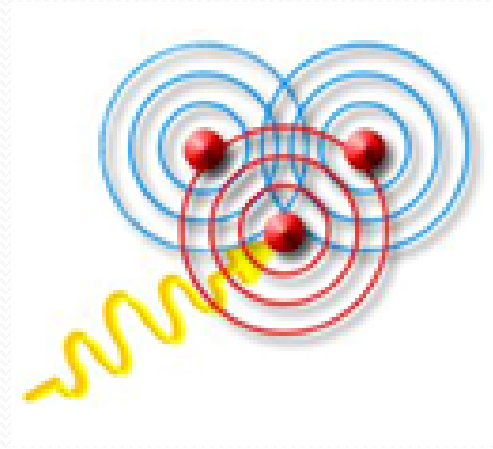
# EXAFS analysis



The EXAFS spectra  $\chi(k)$  of Fe in  $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$  (blue line – annealed in nitrogen, red line – in oxygen)

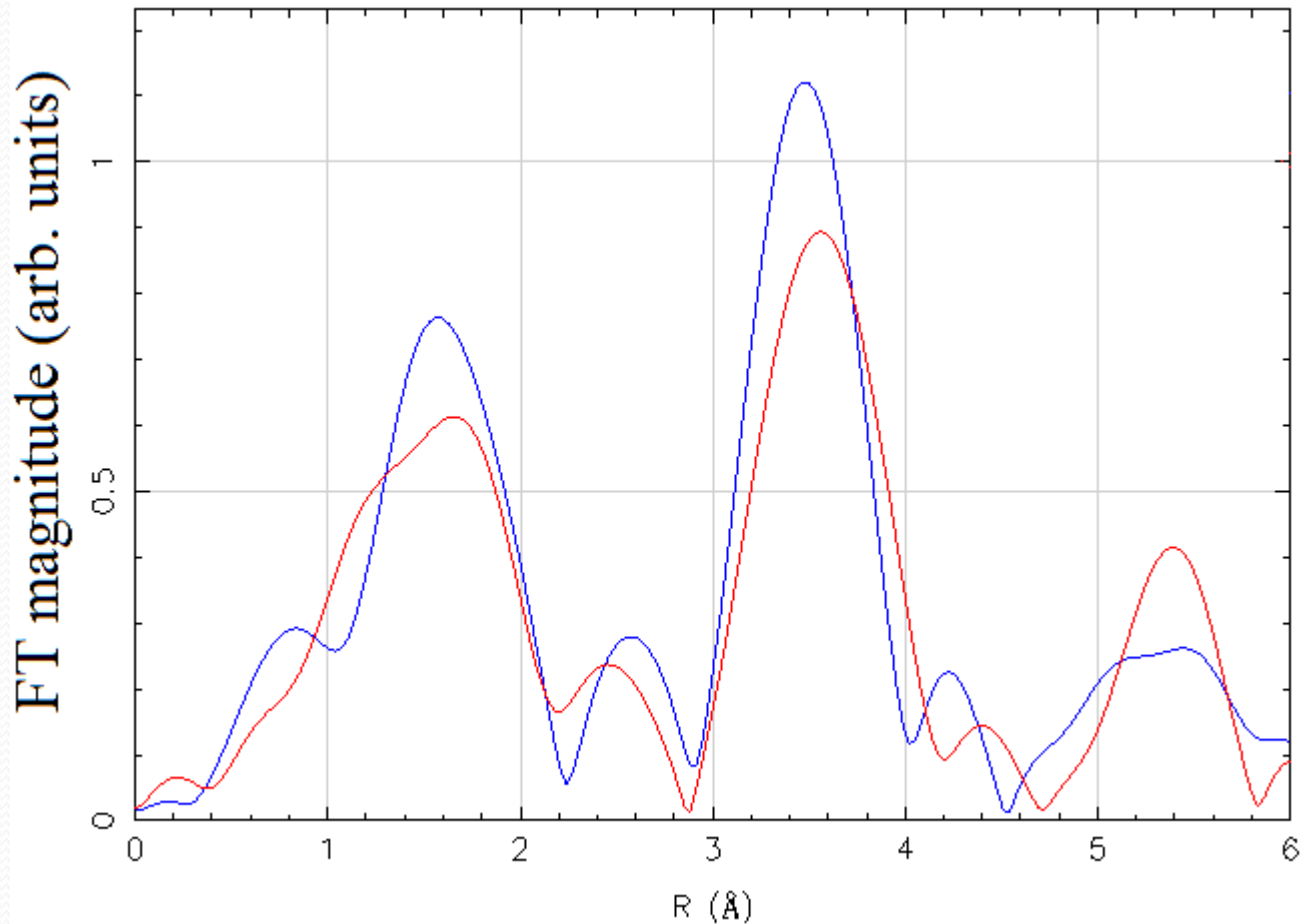
# EXAFS analysis

$$\chi(k) = \sum_i A_i(k) \sin(2kR_i + \delta_i),$$



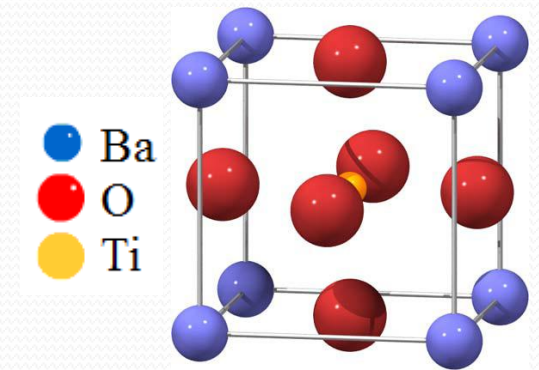
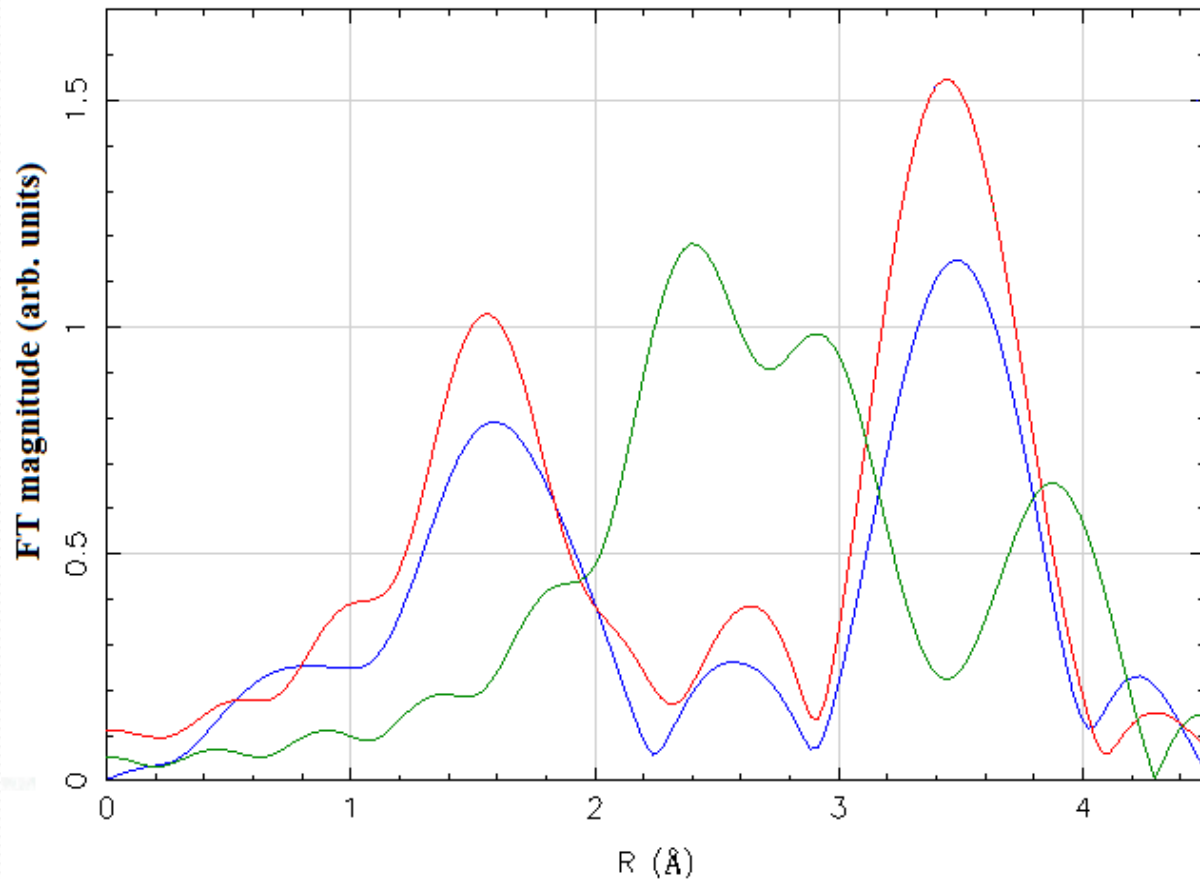
- with the atom-specific phase shift  $\delta_i$  and the amplitude factor

$$A_i(k) = \frac{N_i}{kR_i^2} S_0^2 F_i(k) e^{(-2k^2\sigma_i^2)} e^{-R_i\lambda_i}$$



- Red line - Fe K-edge Fourier transforms of  $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$  annealed in oxygen.
- Blue line - Fe K-edge Fourier transforms of  $\text{Ba}(\text{Ti}_{0.98}\text{Fe}_{0.02})\text{O}_{2.99}$  annealed in nitrogen.

# EXAFS analysis of Fe doped BaTiO<sub>3</sub>

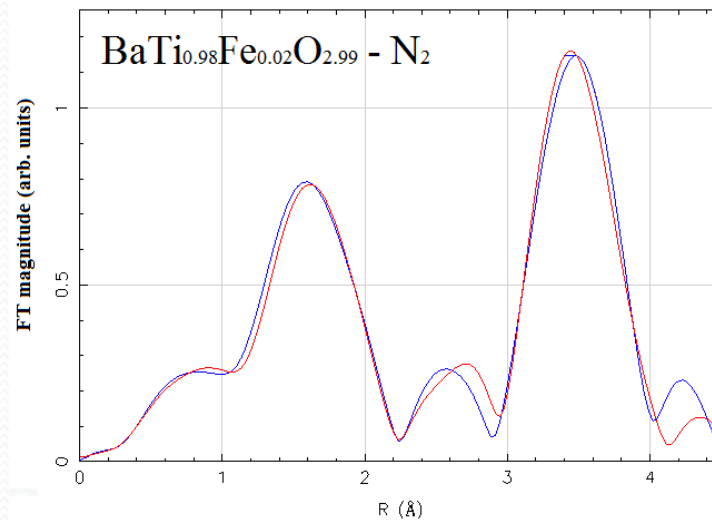
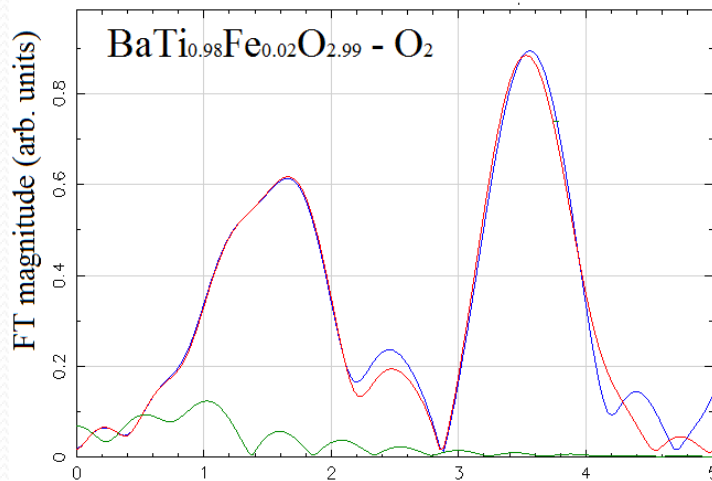
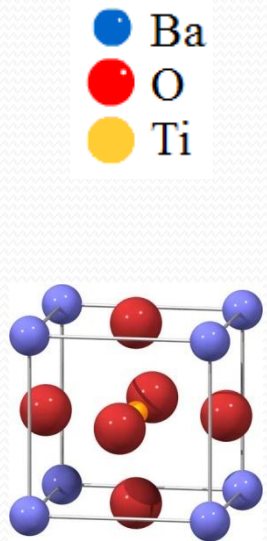


Blue line - Fe K-edge Fourier transforms of Ba(Ti<sub>0.98</sub>Fe<sub>0.02</sub>)O<sub>2.99</sub> (experiment).

Red line - model of the undistorted BaTiO<sub>3</sub> structure around Ti site.

Green line - model of the undistorted BaTiO<sub>3</sub> structure around Ba site.

# EXAFS analysis of Fe doped BaTiO<sub>3</sub>

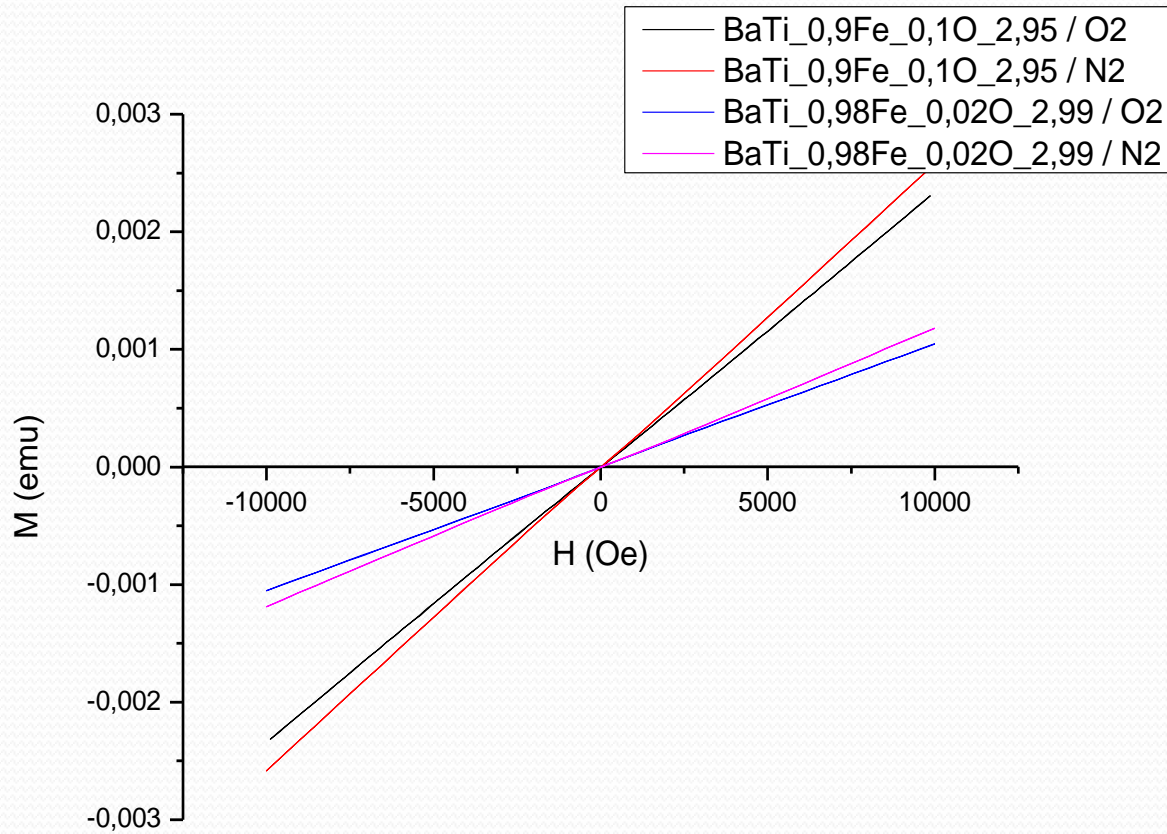


Type	Number	Distance, Å	Debye-Waller factor
O	4	2.05(1)	0.006(4)
O	2	<b>1.90(3)</b>	0.006 (4)
Ba	8	3.44(1)	0.011(1)
Ti	4	4.00(2)	0.012(2)

Type	Number	Distance, Å	Debye-Waller factor
O	4	2.05(1)	0.004(2)
O	2	<b>2.011(8)</b>	0.0014
Ba	8	3.46(1)	0.006
Ti	4	3.98(2)	0.009

$$R_i, \sigma_i^2, N_i$$

# Magnetic measurements



# Conclusion

- We synthesized 4 samples of Fe-doped BaTiO<sub>3</sub> by solid state reaction method.
- No magnetic ordering exists in bulk Fe-doped BaTiO<sub>3</sub>.
- All iron in Ba(Ti<sub>0.98</sub>Fe<sub>0.02</sub>)O<sub>2.99</sub> samples is in trivalent form and Fe<sub>3+</sub> atoms substituted Ti<sub>4+</sub> on B sites of the perovskite BaTiO<sub>3</sub> host matrix.
- No impurities or secondary phases were observed in well-processed Ba(Ti<sub>0.98</sub>Fe<sub>0.02</sub>)O<sub>2.99</sub>.





***Thank you for your  
attention!!!***